# VS-6EWH06FNHM3

Vishay Semiconductors

## Ultralow V<sub>F</sub> Ultrafast Rectifier, 6 A FRED Pt<sup>®</sup>



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TO-252AA (D-PAK)

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Ó1	30
N/C	Anode

PRODUCT SUMMARY						
Package	TO-252AA (D-PAK)					
I <sub>F(AV)</sub>	6 A					
V <sub>R</sub>	600 V					
V <sub>F</sub> at I <sub>F</sub>	1.26 V					
t <sub>rr</sub> (typ.)	18 ns					
T <sub>J</sub> max.	175 °C					
Diode variation	Single die					

#### **FEATURES**

- Hyperfast recovery time, reduced Q<sub>rr</sub> and soft recovery
- 175 °C maximum operating junction temperature
- For PFC CRM/CCM operation
- Low forward voltage drop
- Low leakage current
- AEC-Q101 gualified
- Meets JESD 201 class 2 whisker test
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

#### **DESCRIPTION / APPLICATIONS**

State of the art hyperfast recovery rectifiers designed with optimized performance of forward voltage drop, hyperfast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC boost stage in the AC/DC section of SMPS inverters or as freewheeling diodes. Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Peak repetitive reverse voltage	V <sub>RRM</sub>		600	V		
Average rectified forward current	I <sub>F(AV)</sub>	T <sub>C</sub> = 144 °C	6			
Non-repetitive peak surge current	I <sub>FSM</sub>	T <sub>J</sub> = 25 °C	70	А		
Peak repetitive forward current	I <sub>FM</sub>	$T_{C} = 144 \ ^{\circ}C, f = 20 \ kHz, d = 50 \ \%$	12			
Operating junction and storage temperatures	T <sub>J</sub> , T <sub>Stg</sub>		-65 to +175	°C		

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	$I_{P} = I \cup \cup \cup A$		-	-		
Forward voltage	V <sub>F</sub>	I <sub>F</sub> = 6 A	-	1.60	2.1	V	
		I <sub>F</sub> = 6 A, T <sub>J</sub> = 150 °C	-	1.26	1.7		
Poverso lookago ourrent	1	$V_R = V_R$ rated	-	-	50		
Reverse leakage current I <sub>R</sub>		$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	-	250	μA	
Junction capacitance	CT	V <sub>R</sub> = 600 V	-	3.5	-	pF	
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body	-	8	-	nH	

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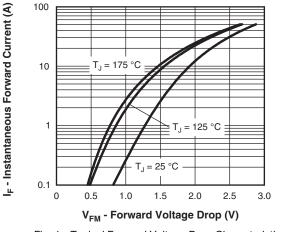
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<b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS		
		$I_F = 1 \text{ A}, dI_F/dt = 10$	00 A/µs, V <sub>R</sub> = 30 V	-	18	25		
Reverse recovery time	+	$I_F = 1 \text{ A}, \text{ d}I_F/\text{d}t = 50 \text{ A}/\mu\text{s}, \text{ V}_R = 30 \text{ V}$		-	22	-		
neverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 25 °C	I <sub>F</sub> = 6 A dI <sub>F</sub> /dt = 200 A/μs V <sub>R</sub> = 390 V	-	27	-	ns	
		T <sub>J</sub> = 125 °C		-	37	-		
Peak recovery current	I <sub>RRM</sub>	T <sub>J</sub> = 25 °C		-	4.1	-	А	
Feak recovery current		T <sub>J</sub> = 125 °C		-	5.3	-		
Reverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	57	-	nC	
		T <sub>J</sub> = 125 °C		-	103	-		

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-65	-	175	°C
Thermal resistance, junction to case per leg	R <sub>thJC</sub>		-	-	3	°C/W
Approximate weight				0.3		g
			0.01 o		oz.	
Marking device		Case style D-PAK		6EWH	06FNH	



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Fig. 1 - Typical Forward Voltage Drop Characteristics

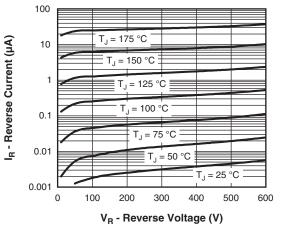


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

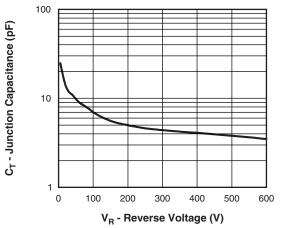


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

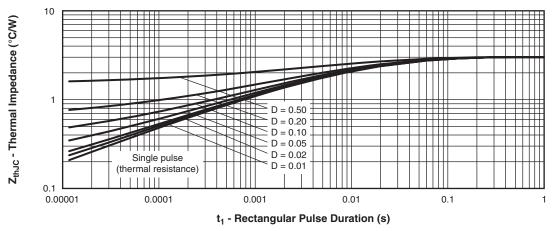
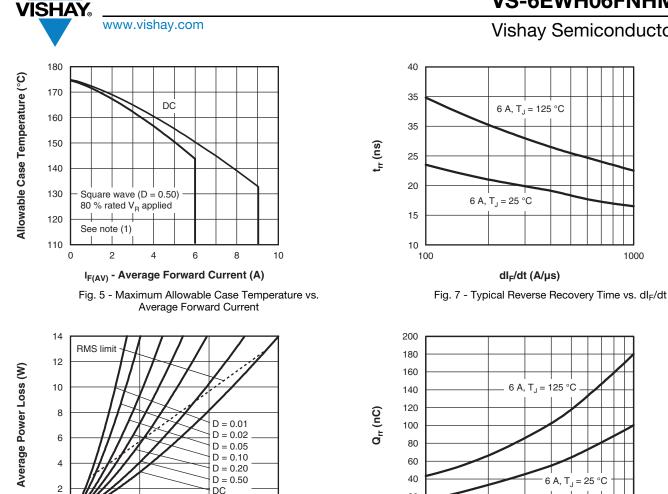


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics



9



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1000

1000

dl<sub>F</sub>/dt (A/µs)

Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt



0

0

<sup>(1)</sup> Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ;  $\begin{array}{l} \mathsf{Pd} = \mathsf{Forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \, x \ \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{Inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \ x \ \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} \ \mathsf{-D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{Rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$ 

I<sub>F(AV)</sub> - Average Forward Current (A)

6

Fig. 6 - Forward Power Loss Characteristics

3

20

0

100

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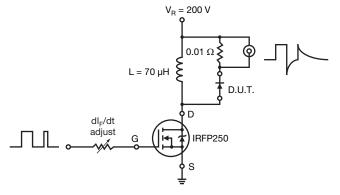


Fig. 9 - Reverse Recovery Parameter Test Circuit

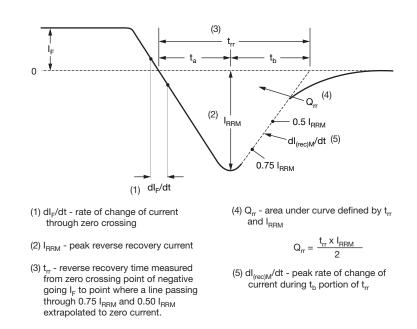


Fig. 10 - Reverse Recovery Waveform and Definitions



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#### **ORDERING INFORMATION TABLE**

Device code	VS-	6	Е	w	н	06	FN	TRL	н	M3
		2	3	4	5	6	7	8	9	10
	2									
	4	- Pac	single c kage id D-PAK	entifier:						
	6	- Voli - FN	H = hyperfast recovery Voltage rating (06 = 600 V) FN = TO-252AA							
	8	• TI	<ul> <li>None = tube</li> <li>TR = tape and reel</li> <li>TRL = tape and reel (left oriented)</li> </ul>							
	9 10	- H = - Env	AEC-Q	be and r 101 qua ntal digit	alified		-	torming	tionala	ad (Pb)-1

ORDERING INFORMATION (Example)								
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION					
VS-6EWH06FNHM3	75	3000	Antistatic plastic tube					
VS-6EWH06FNTRHM3	2000	2000	13" diameter reel					
VS-6EWH06FNTRRHM3	3000	3000	13" diameter reel					
VS-6EWH06FNTRLHM3	3000	3000	13" diameter reel					

LINKS TO RELATED DOCUMENTS						
Dimensions	www.vishay.com/doc?95519					
Part marking information	www.vishay.com/doc?95518					
Packaging information	www.vishay.com/doc?95033					



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